

Tantalum, MnO2 Tantalum, High Temperature, T499, 1 uF, 10%, 25 V, 3216, SMD, MnO2, Molded, Hi-Temp, 175C, Auto, AEC-Q200, N/A, 8 Ohms, 1.8mm



General Information	
Dielectric:	MnO2 Tantalum
Style:	SMD Chip
Series:	T499
Description:	SMD, MnO2, Molded, Hi-Temp, 175C, Auto, AEC-Q200
Features:	High Temperature, Automotive
RoHS:	Yes
Termination:	Tin
Approvals:	AEC-Q200
AEC-Q200:	Yes

Dimensions	
Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
H	1.6mm +/-0.2mm
T	0.13mm REF
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
A	1.2mm MIN
B	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
P	0.4mm REF
R	0.4mm REF
X	0.1mm +/-0.1mm

Specifications	
Capacitance:	1 uF
Capacitance Tolerance:	10%
Voltage DC:	25 VDC (85C), 19.44 VDC (125C), 12.5 VDC (175C)
Temperature Range:	-55/+175C
Dissipation Factor:	4%
Failure Rate:	N/A
Resistance:	8000 mOhms (100kHz)
Current:	97 mAmps (25C), 87.3 mAmps (85C), 19.4 mAmps (175C)
Leakage:	0.5 uAmps

Packaging Specifications	
Weight:	58.6 mg
Packaging:	T&R, 178mm
Packaging Quantity:	2000

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